



### LM2902/LM2904

DUAL AND QUAD OPERATIONAL AMPLIFIERS

### Description

The LM2902/LM2904 series amplifiers consist of four and two independent high-gain operational amplifiers with very low input offset voltage specification. They have been designed to operate from a single power supply over a wide range of voltages; however operation from split power supplies is also possible. They offer low power supply current independent of the magnitude of the power supply voltage.

The LM2902/LM2904 series are characterized for operation from -40°C to +125°C and the dual devices are available in SO-8, MSOP-8, TSSOP-8 and the quad devices available in SO-14 and TSSOP-14 with industry standard pin-outs. Both use green mold compound as

### Features

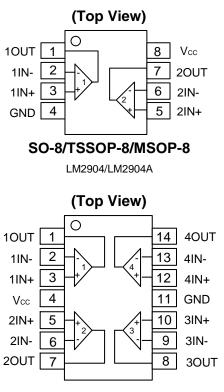
standard.

- Wide Power Supply Voltage Range:
  - Single Supply: 3V to 36V
  - Dual Supplies: ±1.5V to ±18V
- Very Low Supply Current Drain
  - LM2904 500µA Independent of Supply Voltage
  - LM2902 700µA Independent of Supply Voltage
- Low Input Bias Current: 20nA
- Low Input Offset Voltage:
  - A Version: 1mV Typ
- Non-A Version: 2mV Typ
- Large DC Voltage Gain: 100dB
- Wide Bandwidth (Unity Gain): 700kHz (Temperature Compensated)
- Internally Compensated with Unity Gain
- Input Common-Mode Voltage Range Includes Ground
- Differential Input Voltage Range Equal to the Power Supply Voltage
- Large Output Voltage Swing: 0V to V<sub>CC</sub> -1.5V
- SO-8, MSOP-8, TSSOP-8 (Duals) and SO-14, TSSOP-14 (Quads) Packages Available
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>LM2902Q\_LM2904Q</u>)

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

### Pin Assignments

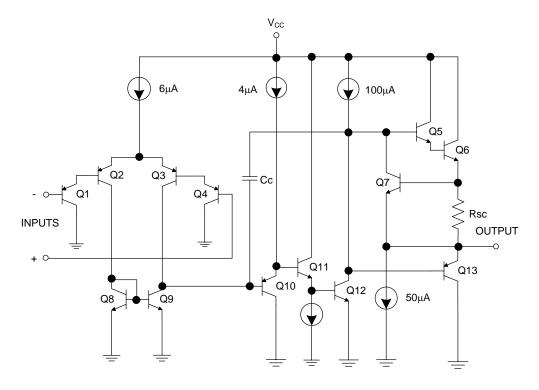


SO-14/TSSOP-14

LM2902/LM2902A



# Functional Block Diagram



Each Amplifier

# **Pin Descriptions**

LM2902, LM2902A		
Pin Name	Pin Number	Function
10UT	1	Channel 1 Output
1IN-	2	Channel 1 Inverting Input
1IN+	3	Channel 1 Non-Inverting Input
Vcc	4	Chip Supply Voltage
2IN+	5	Channel 2 Non-Inverting Input
2IN-	6	Channel 2 Inverting Input
2OUT	7	Channel 2 Output
3OUT	8	Channel 3 Output
3IN-	9	Channel 3 Inverting Input
3IN+	10	Channel 3 Non-Inverting Input
GND	11	Ground
4IN+	12	Channel 4 Non-Inverting Input
4IN-	13	Channel 4 Inverting Input
40UT	14	Channel 4 Output
LM2904, LM2904A		
10UT	1	Channel 1 Output
1IN-	2	Channel 1 Inverting Input
1IN+	3	Channel 1 Non-Inverting Input
GND	4	Ground
2IN+	5	Channel 2 Non-Inverting Input
2IN-	6	Channel 2 Inverting Input
2OUT	7	Channel 2 Output
V <sub>CC</sub>	8	Chip Supply Voltage



Notes:

# Absolute Maximum Ratings (Note 4) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	F	Parameter	Rating	Unit
Vcc	Supply Voltage		±18 or 36	V
VID	Differential Input Voltage		36	V
V <sub>IN</sub>	Input Voltage		-0.3 to +36	V
		SO-8	TBD	
	De che est The second laws a de second	MSOP-8	TBD	
θ <sub>JA</sub>	Package Thermal Impedance (Note 5)	TSSOP-8	TBD	°C/W
	(10010-5)	SO-14	TBD	
		TSSOP-14	TBD	
		SO-8	TBD	
	De che est The second laws a de second	MSOP-8	TBD	
θ <sub>JC</sub>	Package Thermal Impedance (Note 6)	TSSOP-8	TBD	°C/W
	(1000 0)	SO-14	TBD	
		TSSOP-14	TBD	
_	Output Short-Circuit to GND (One Amplifier) (Note 7)	$V_{CC} \le 15V$ and $T_A = +25^{\circ}C$	Continuous	-
T <sub>A</sub>	Operating Temperature Range		-40 to +125	°C
TJ	Operating Junction Temperature		+150	°C
T <sub>ST</sub>	Storage Temperature Range		-65 to +150	°C
	Human Body Mode ESD Protection	n (Note 8)	300	V
ESD	Machine Mode ESD Protection		150	v

4. Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5. Maximum power dissipation is a function of  $T_{J(max)}$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is

 $P_{D} = (T_{J(max)} - T_{A})/\theta_{JA}.$  Operating at the absolute maximum T\_{J} of +150°C can affect reliability. 6. Maximum power dissipation is a function of T\_J(max),  $\theta_{JC}$ , and T<sub>A</sub>. The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_{J(max)} - T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of +150°C can affect reliability.

7. Short circuits from outputs to  $V_{CC}$  or ground can cause excessive heating and eventual destruction.

8. Human body model,  $1.5k\Omega$  in series with 100pF.



### Electrical Characteristics (Notes 12 & 13) (@ V<sub>CC</sub> = +5.0V, T<sub>A</sub> = +25°C, unless otherwise specified.)

M2902	I M2902A	

_M2902, L			<b>0</b> 11/1		<b>-</b>	M.*	<b>T</b>	M	11
	Parameter		Conditions		TA	Min	Тур	Max	Unit
			$V_{IC} = V_{CMR} Min,$	Non-A Device	T <sub>A</sub> = +25°C	—	2	7	
Vio	Input Offset Voltage	out Offset Voltage			Full Range	—	—	10	mV
10			$V_{CC} = 5V$ to Max,	A-Suffix Device	$T_A = +25^{\circ}C$	—	1	2	
			$R_{S} = 0\Omega$		Full Range	—	—	4	
$\Delta V_{IO}/\Delta T$	Input Offset Voltage T Drift	Femperature	$R_S = 0\Omega$		Full Range	_	7		µV/°C
IB	Input Bias Current		$I_{\text{IN+}}$ or $I_{\text{IN-}}$ with OUT in	Linear Range,	T <sub>A</sub> = +25°C	—	-20	-200	nA
чВ	input blub ounont		V <sub>CMR</sub> = 0V (Note 9)		Full Range	—	—	-500	10.0
I <sub>IO</sub>	Input Offset Current		I <sub>IN+</sub> - I <sub>IN-</sub> , V <sub>CM</sub> = 0V		T <sub>A</sub> = +25°C	—	2	50	nA
UU			IIN+ - IIN−, VCM – OV		Full Range	—	—	150	11/5
$\Delta I_{10} / \Delta T$	Input Offset Current T Drift	emperature	_		Full Range	—	10	—	pA/°C
	Input Common-Mode	Voltage		-		0 to V <sub>CC</sub> -1.5	—	_	
V <sub>CMR</sub> Range		,ĝ.	V <sub>CC</sub> = 30V (Note 10)		Full Range	0 to V <sub>CC</sub> -2.0	—	_	V
	Supply Current		$V_0 = 0.5 V_{CC}$ , No Load	$V_{CC} = 30V$	Full Range	—	1.0	3.0	m۸
I <sub>CC</sub>	(Four Amplifiers)		$V_0 = 0.5 V_{CC}$ , No Load	$V_{CC} = 5V$	Full Range	—	0.7	1.2	mA
•	Valtage Coin		$\label{eq:V_CC} \begin{split} V_{CC} &= 15 V,  V_{OUT} = 1 V \text{ to } 11 V, \\ R_L &\geq 2 k \Omega \end{split}$		T <sub>A</sub> = +25°C	25	100	_	V/mV
Av	Voltage Gain				Full Range	15	—	_	
CMRR	Common Mode Reject	ction Ratio	DC, $V_{CMR} = 0V$ to $V_{CC}$ -	1.5V	T <sub>A</sub> = +25°C	60	70	_	dB
PSRR	Power Supply Rejecti	on Ratio	$V_{CC} = 5V$ to $30V$		T <sub>A</sub> = +25°C	70	100		dB
_	Amplifier to Amplifier	Coupling	f = 1kHz to 20kHz (Inpu (Note 11)	ut Referred)	T <sub>A</sub> = +25°C	_	-120	_	dB
		O'ra ha	$V_{IN} = 1V, V_{IN}^{+} = 0V, V_{C}$ $V_{O} = 200mV$	<sub>C</sub> = 15V,	T <sub>A</sub> = +25°C	12	50	_	μA
ISINK	Output Current	Sink	$V_{IN}^{-} = 1V, V_{IN}^{+} = 0V, V_{C}$	<sub>c</sub> = 15V,	T <sub>A</sub> = +25°C	10	20	_	
	Output Current		Vo = 15V		Full Range	5	—	_	
1		Source	$V_{IN}^{+} = 1V, V_{IN}^{-} = 0V, V_{C}$	<sub>C</sub> = 15V,	T <sub>A</sub> = +25°C	-20	-40	-60	mA
SOURCE		Source	$V_{O} = 0V$		Full Range	-10	—	_	]
I <sub>SC</sub>	Short-Circuit to Grour	nd	$V_{CC} = 5V$ , $GND = -5V$ , $V_O = 0V$		$T_A = +25^{\circ}C$	—	±40	±60	mA
			$R_L = 10k\Omega$		T <sub>A</sub> = +25°C	—	V <sub>CC</sub> -1.5	_	
V <sub>OH</sub>	High-Level Output Vo	ltage Swing	$R_L =$	2kΩ		26	—	_	V
			$V_{CC} = 30V$ $R_L \ge$	10kΩ	Full Range	27	28	_	
Vol	Low-Level Output Vol	Itage Swing	$R_L \leq 10k\Omega$		Full Range	_	5	20	mV

# AC Electrical Characteristics (Notes 12 & 13) (@ V<sub>CC</sub> = ±15.0V, T<sub>A</sub> = +25°C, unless otherwise specified.)

LM2902, LM2902A						
	Parameter	Conditions	Тур	Unit		
SR	Slew Rate at Unity Gain	$R_L = 1M\Omega, C_L = 30pF, V_I = \pm 10V$	0.3	V/µs		
B1	Unity Gain Bandwidth	$R_L = 1M\Omega, C_L = 20pF$	0.7	MHz		
Vn	Equivalent Input Noise Voltage	$R_{S} = 100\Omega, V_{I} = 0V, f = 1kHz$	40	nV/√Hz		

Notes: 9. The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so no loading change exists on the input lines.

10. The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than 0.3V (@ +25°C). The upper end of the common-mode voltage range is  $V_{CC}$  -1.5V (@ +25°C), but either or both inputs can go to +36V without damage, independent of the magnitude of  $V_{CC}$ .

11. Due to proximity of external components, insure that coupling is not originating via stray capacitance between these external parts. This typically can be detected as this type of capacitance increases at higher frequencies.

12. Typical values are all at T<sub>A</sub> = +25°C conditions and represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.

13. All limits are guaranteed by testing or statistical analysis. Limits over the full temperature are guaranteed by design, but not tested in production.



### Electrical Characteristics (Cont.) (Notes 12 & 13) (@ V<sub>CC</sub> = +5.0V, T<sub>A</sub> = +25°C, unless otherwise specified.)

LM2904, L	M2904A									
	Parameter		Conditions		TA	Min	Тур	Мах	Unit	
			V <sub>IC</sub> = V <sub>CMR</sub> Min,	No	n-A Device	T <sub>A</sub> = +25°C	_	2	7	
Vio	Input Offset Volt	ltago	V <sub>O</sub> = 1.4V,	INOI	II-A Device	Full Range	_	_	10	mV
VIO		aye	$V_{CC} = 5V$ to Max	۵.9	Suffix Device	$T_A = +25^{\circ}C$	_	1	2	IIIV
			$R_{S} = 0\Omega$	<u>_</u>		Full Range	—	_	4	
$\Delta V_{IO} / \Delta T$	Input Offset Volt Drift	age Temperature	$R_S = 0\Omega$			Full Range	—	7	—	µV/°C
IB	Input Bias Curre	nt	$I_{IN+}$ or $I_{IN-}$ with OU	IT in Line	ear Range,	$T_A = +25^{\circ}C$	—	-20	-250	nA
ıВ	Input Dias Ouric	in a second s	V <sub>CMR</sub> = 0V (Note 9	9)		Full Range	—	_	-500	117
lio	Input Offset Cur	ront	I <sub>IN+</sub> - I <sub>IN-</sub> , V <sub>CM</sub> = 0\			$T_A = +25^{\circ}C$	—	2	50	nA
ιO	input onset our	lent	$\eta_{N+} = \eta_{N-}, v_{CM} = 0.0$	v		Full Range	—	_	150	117
$\Delta I_{IO} / \Delta T$	Input Offset Cur Drift	rent Temperature		_		Full Range	—	10	—	pA/°C
	Input Common-I	Mode Voltage			T <sub>A</sub> = +25°C	0 to V <sub>CC</sub> -1.5	_	_		
V <sub>CMR</sub>	Range		V <sub>CC</sub> = 30V (Note 10)		Full Range	0 to V <sub>CC</sub> -2.0	_	_	V	
	Supply Current		V <sub>O</sub> = 0.5V <sub>CC</sub> , No L	oad	$V_{CC} = 30V$	Full Range	_	0.7	2.0	
ICC	(Two Amplifiers)		V <sub>O</sub> = 0.5V <sub>CC</sub> , No L	oad	$V_{CC} = 5V$	Full Range	_	0.5	1.2	mA
Δ	Voltage Gain		$V_{CC} = 15V, V_{OUT} = 1V$ to 11V, R <sub>L</sub> ≥ 2kΩ		$T_A = +25^{\circ}C$	25	100	—	V/mV	
A <sub>V</sub>	Voltage Gain				Full Range	15	_	_		
CMRR	Common Mode	Rejection Ratio	DC, $V_{CMR} = 0V$ to $V_{CC}$ -1.5V		$T_A = +25^{\circ}C$	60	70	—	dB	
PSRR	Power Supply R	ejection Ratio	$V_{CC} = 5V$ to 30V		$T_A = +25^{\circ}C$	70	100	—	dB	
—	Amplifier to Amp	lifier Coupling	f = 1kHz to 20kHz (Note 11)		$T_A = +25^{\circ}C$	_	120	—	dB	
			$V_{IN}^{-} = 1V, V_{IN}^{+} = 0V$ $V_{O} = 200mV$	V, V <sub>CC</sub> =	15V,	T <sub>A</sub> = +25°C	12	50	_	μA
ISINK		Sink				T <sub>A</sub> = +25°C	10	20	_	
	Output Current		$V_{IN} = 1V, V_{IN} = 0V$	$V, V_{CC} =$	15V, V <sub>O</sub> = 15V	Full Range	5	_	_	
		0				T <sub>A</sub> = +25°C	-20	-40	-60	mA
ISOURCE		Source	$V_{\rm IN} = 1V$ , $V_{\rm IN} = 0V$ , $V_{\rm CC} = 15V$ , $V_{\rm CC} = 0V$		Full Range	-10	_	—	1	
I <sub>SC</sub>	Short-Circuit to	o Ground $V_{CC} = 5V, GND = -5V, V_O = 0V$		T <sub>A</sub> = +25°C	_	±40	±60	mA		
			$R_L = 10k\Omega$			T <sub>A</sub> = +25°C	V <sub>CC</sub> -1.5	_	_	
Vон	High-Level Outp	ut Voltage Swing	V 00V	$R_L = 2kg$	Ω		26	—	—	V
		-	$V_{CC} = 30V$	R <sub>L</sub> ≥ 10I		Full Range	27	28	_	
Vol	Low-Lever Outp	ut Voltage Swing	$R_L \leq 10 k \Omega$			Full Range	_	5	20	mV

### AC Electrical Characteristics (Notes 12 & 13) (@ V<sub>CC</sub> = ±15.0V, T<sub>A</sub> = +25°C, unless otherwise specified.)

LM2904, LM2904A						
	Parameter	Conditions	Тур	Unit		
SR	Slew Rate at Unity Gain	$R_L = 1M\Omega$ , $C_L = 30pF$ , $V_I = \pm 10V$	0.3	V/µs		
B1	Unity Gain Bandwidth	$R_L = 1M\Omega, C_L = 20pF$	0.7	MHz		
Vn	Equivalent Input Noise Voltage	$R_{S} = 100\Omega, V_{I} = 0V, f = 1kHz$	40	nV/√Hz		

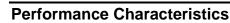
Notes: 9. The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so no loading change exists on the input lines.

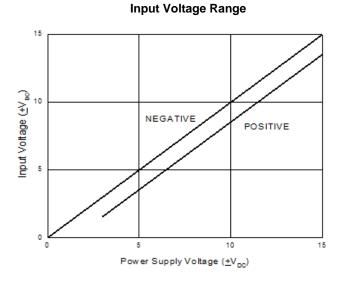
10. The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than 0.3V (@ +25°C). The upper end of the common-mode voltage range is V<sub>CC</sub> -1.5V (@ +25°C), but either or both inputs can go to +36V without damage, independent of the magnitude of V<sub>CC</sub>.

11. Due to proximity of external components, insure that coupling is not originating via stray capacitance between these external parts. This typically can be detected as this type of capacitance increases at higher frequencies.

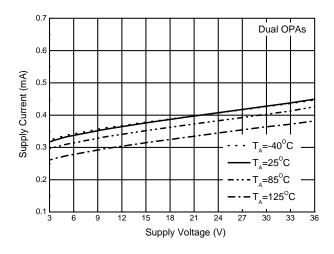
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13. All limits are guaranteed by testing or statistical analysis. Limits over the full temperature are guaranteed by design, but not tested in production.

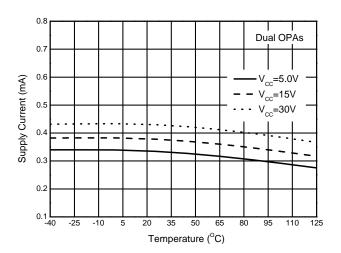


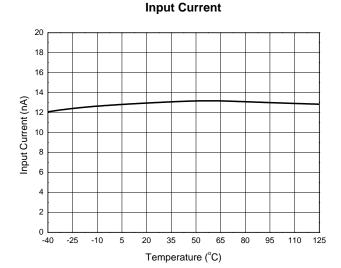


### Supply Current vs. Supply Voltage (LM2904/LM2904A)

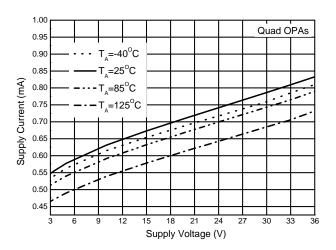


Supply Current vs. Temperature (LM2904/LM2904A)

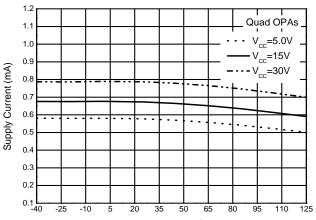




### Supply Current vs. Supply Voltage (LM2902/LM2902A)

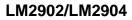


Supply Current vs. Temperature (LM2902/LM2902A)



Temperature (°C)

LM2902/LM2904 Document number: DS36780 Rev. 4 - 2

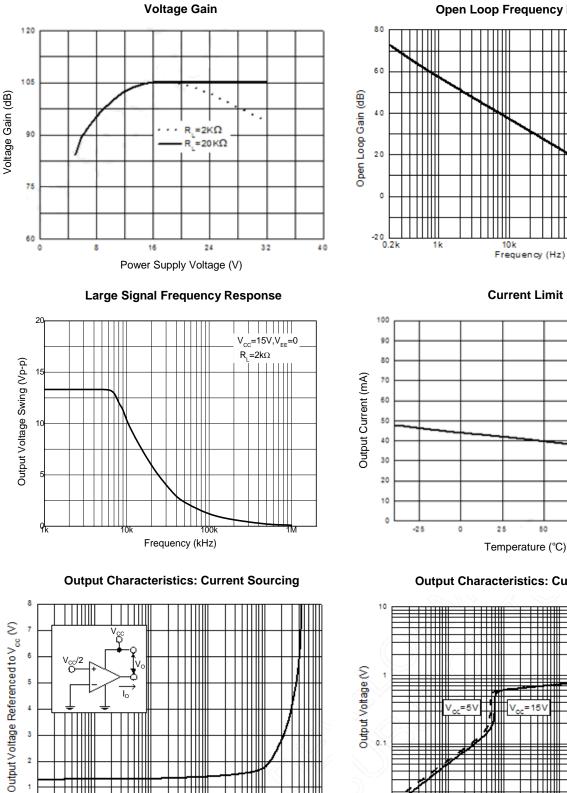


1M 2M

V cc=30V, V cc=0V R, =2kΩ, C, =100pF



# Performance Characteristics (Cont.)

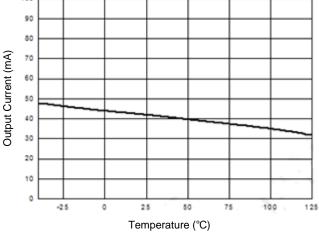


**Open Loop Frequency Response** 

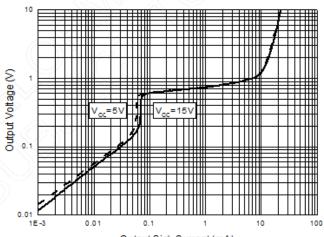
**Current Limit** 

100k

10k



**Output Characteristics: Current Sinking** 



Output Sink Current (mA)

LM2902/LM2904 Document number: DS36780 Rev. 4 - 2

0.01

0.1

Output Source Current (mA)

3

2

1

0

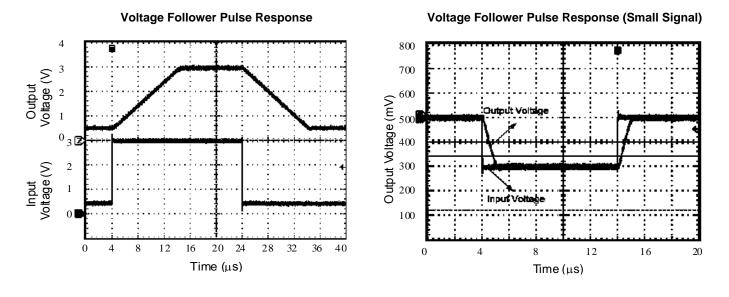
1E-3

100

10



## Performance Characteristics (Cont.)





### **Application Information**

#### **General Information**

The LM2902/LM2904 series are op amps which operate with only a single power supply voltage, have true-differential inputs, and remain in the linear mode with an input common-mode voltage of  $0V_{DC}$ . These amplifiers operate over a wide range of power supply voltage with little change in performance characteristics. At +25°C amplifier operation is possible down to a minimum supply voltage of 2.3V<sub>DC</sub>.

Precautions should be taken to insure that the power supply for the integrated circuit never becomes reversed in polarity or that the unit is not inadvertently installed backwards in a test socket as an unlimited current surge through the resulting forward diode within the IC could cause fusing of the internal conductors and result in a destroyed unit.

Large differential input voltages can be easily accommodated and, as input differential voltage protection diodes are not needed, no large input currents result from large differential input voltages. The differential input voltage may be larger than V<sup>+</sup> without damaging the device. Protection should be provided to prevent the input voltages from going negative more than -0.3V<sub>DC</sub> (@ +25°C). An input clamp diode with a resistor to the IC input terminal can be used.

To reduce the power supply current drain, the amplifiers have a Class A output stage for small signal levels which converts to Class B in a large signal mode. These allow the amplifiers to both source and sink large output currents. Therefore both NPN and PNP external current boost transistors can be used to extend the power capability of the basic amplifiers. The output voltage needs to raise approximately 1 diode drop above ground to bias the on-chip vertical PNP transistor for output current sinking applications.

For AC applications, where the load is capacitive coupled to the output of the amplifier, a resistor should be used, from the output of the amplifier to ground to increase the Class A bias current and prevent crossover distortion. Where the load is directly coupled, as in DC applications, there is no crossover distortion.

Capacitive loads which are applied directly to the output of the amplifier reduce the loop stability margin. Values of 50pF can be accommodated using the worst-case non-inverting unity gain connection. Large closed loop gains or resistive isolation should be used if larger load capacitance must be driven by the amplifier.

The bias network of the LM2902/LM2904 series establishes a quiescent current which is independent of the magnitude of the power supply voltage over the range of  $3V_{DC}$  to  $30V_{DC}$ .

Output short circuits either to ground or to the positive power supply should be of short time duration. Units can be destroyed, not as a result of the short circuit current causing metal fusing, but rather due to the large increase in IC chip dissipation which will cause eventual failure due to excessive function temperatures. Putting direct short-circuits on more than one amplifier at a time will increase the total IC power dissipation to destructive levels, if not properly protected with external dissipation limiting resistors in series with the output leads of the amplifiers. The larger value of output source current which is available at +25°C provides a larger output current capability at elevated temperatures (see Performance Characteristics) than a standard IC op amp.

The circuits presented in the section on typical applications emphasize operation on only a single power supply voltage. If complementary power supplies are available, all of the standard op amp circuits can be used. In general, introducing a pseudo-ground (a bias voltage reference of  $V_{CC}/2$ ) will allow operation above and below this value in single power supply systems. Many application circuits are shown which take advantage of the wide input common-mode voltage range which includes ground. In most cases, input biasing is not required and input voltages which range to ground can easily be accommodated.

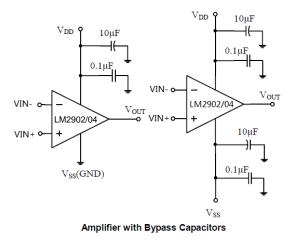


### Application Information (Cont.)

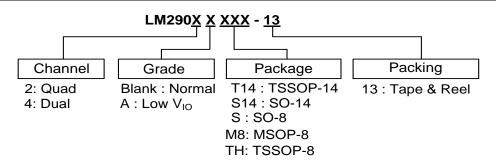
#### Power Supply Bypassing and Layout

The LM2902/LM2904 operate both single supply voltage range 3V to 36V or dual supply voltage ±1.5V to ±18V.

As with any operation amplifier, proper supply bypassing is critical for low noise performance and high power supply rejection. For single supply operation system, a minimum  $0.1\mu$ F bypass capacitor should be recommended to place as close as possible between the V<sub>CC</sub> Pin and GND. For dual supply operation, both the positive supply pin and negative supply pin should be bypassed to ground with a separate  $0.1\mu$ F ceramic capacitor. 2.2 $\mu$ F tantalum capacitor can be added for better performance. Keep the length of leads and traces that connect capacitors between the LM2902/LM2904 power supply pin and ground as short as possible.



### Ordering Information (Note 14)



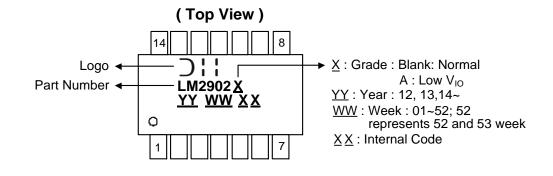
Part Number	Baakaga Cada	Paakaging	13" Tape	and Reel
Part Number	Package Code	Packaging	Quantity	Part Number Suffix
LM2902T14-13	T14	TSSOP-14	2,500/Tape & Reel	-13
LM2902AT14-13	T14	TSSOP-14	2,500/Tape & Reel	-13
LM2902S14-13	S14	SO-14	2,500/Tape & Reel	-13
LM2902AS14-13	S14	SO-14	2,500/Tape & Reel	-13
LM2904S-13	S	SO-8	2,500/Tape & Reel	-13
LM2904AS-13	S	SO-8	2,500/Tape & Reel	-13
LM2904AM8-13	M8	MSOP-8	2,500/Tape & Reel	-13
LM2904M8-13	M8	MSOP-8	2,500/Tape & Reel	-13
LM2904ATH-13	TH	TSSOP-8	2,500/Tape & Reel	-13
LM2904TH-13	TH	TSSOP-8	2,500/Tape & Reel	-13

Note: 14. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

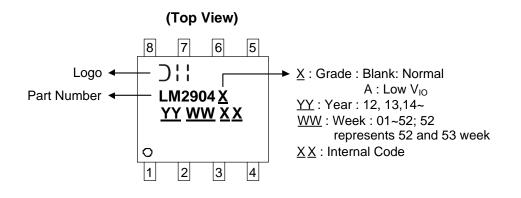


# Marking Information

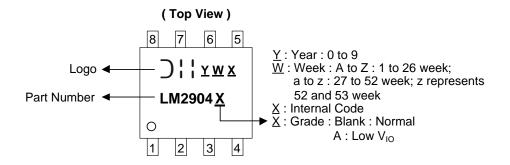
#### (1) TSSOP-14 and SO-14



(2) SO-8



(3) MSOP-8 and TSSOP-8

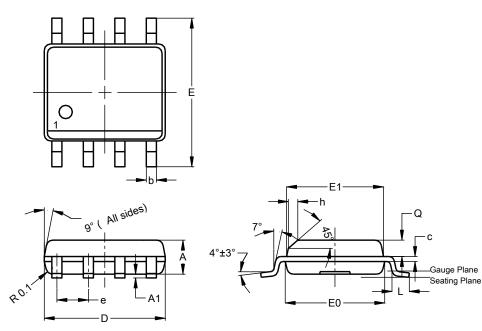




# **Package Outline Dimensions**

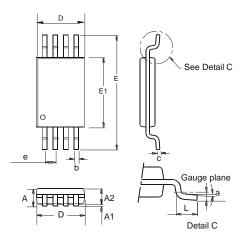
Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (1) Package Type: SO-8



	SO-8					
Dim	Min	Max	Тур			
Α	1.40	1.50	1.45			
A1	0.10	0.20	0.15			
b	0.30	0.50	0.40			
С	0.15	0.25	0.20			
D	4.85	4.95	4.90			
E	5.90	6.10	6.00			
E1	3.80	3.90	3.85			
E0	3.85	3.95	3.90			
е			1.27			
h	-		0.35			
L	0.62	0.82	0.72			
Q	0.60	0.70	0.65			
All	Dimens	sions in	mm			

#### (2) Package Type: TSSOP-8



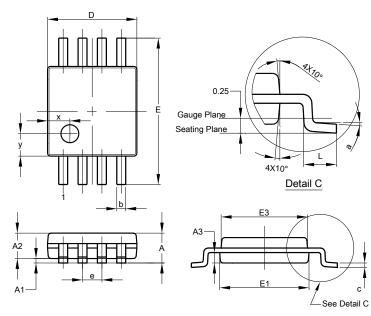
	TSSOP-8					
Dim	Min	Max	Тур			
а	0.09	-	-			
Α		1.20	-			
A1	0.05	0.15	-			
A2	0.825	1.025	0.925			
b	0.19	0.30	-			
С	0.09	0.20	-			
D	2.90	3.10	3.025			
е	-	-	0.65			
Е	-	-	6.40			
E1	4.30	4.50	4.425			
L	0.45	0.75	0.60			
AI	I Dimens	sions in	mm			



# Package Outline Dimensions (Cont.)

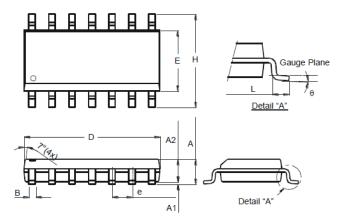
Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (3) Package Type:MSOP-8

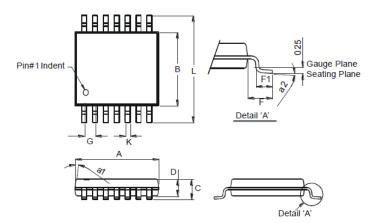


MSOP-8						
Dim	Min	Max	Тур			
Α	-	1.10	-			
A1	0.05	0.15	0.10			
A2	0.75	0.95	0.86			
A3	0.29	0.49	0.39			
b	0.22	0.38	0.30			
С	0.08	0.23	0.15			
D	2.90	3.10	3.00			
Е	4.70	5.10	4.90			
E1	2.90	3.10	3.00			
E3	2.85	3.05	2.95			
е	-	-	0.65			
L	0.40	0.80	0.60			
а	0°	8°	4°			
х	-	-	0.750			
У	-	-	0.750			
	Dimen	sions	in mm			

(4) Package Type: SO-14



(5) Package Type: TSSOP-14



SO-14				
Dim	Min	Max		
Α	1.47	1.73		
A1	0.10	0.25		
A2	1.45	Тур		
В	0.33	0.51		
D	8.53	8.74		
E	3.80	3.99		
е	1.27	Тур		
Н	5.80	6.20		
L	0.38	1.27		
θ	0°	8°		
All Dimensions in mm				

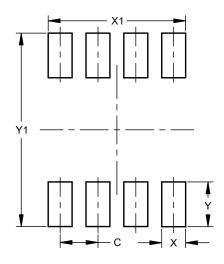
TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
Α	4.9	5.10
В	4.30	4.50
С	-	1.2
D	0.8	1.05
F	1.00	Тур
F1	0.45	0.75
G	0.65 Typ	
K	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		



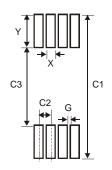
# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

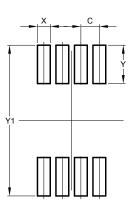
#### (1) Package Type: SO-8



(2) Package Type: TSSOP-8



(3) Package Type:MSOP-8



Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50

Dimensions	Value (in mm)
Х	0.45
Y	1.78
C1	7.72
C2	0.65
C3	4.16
G	0.20

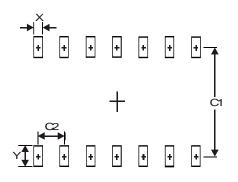
Dimensions	Value (in mm)
C	0.650
Х	0.450
Y	1.350
Y1	5.300



# Suggested Pad Layout (Cont.)

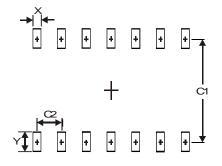
Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (4) Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

#### (5) Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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